

Description

The IRFH8324PBF uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

Pin 1

DFN5X6-8L

General Features

 $V_{DS} = 30 \text{ V } I_{D} = 120 \text{ A}$

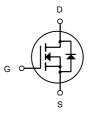
 $R_{DS(ON)}$ < 4.4 m V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
IRFH8324PBF	DFN5X6-8L	HXY MOSFET	5000

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Symbol	Parameter	Rating	Units	
Vps	Drain-Source Voltage	30	V	
Vgs	Gate-Source Voltage ±20		V	
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ^{1,6}	Continuous Drain Current, V _{GS} @ 10V ^{1.6} 120		
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ^{1,6}	А		
Ідм	Pulsed Drain Current ² 320		А	
EAS	Single Pulse Avalanche Energy ³ 180		mJ	
las	Avalanche Current	60	А	
P _D @T _C =25°C	Total Power Dissipation ⁴	187	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range -55 to 150		°C	
R _θ JA	Thermal Resistance Junction-Ambient ¹ 62		°C/W	
Rejc	Reuc Thermal Resistance Junction-Case ¹		°C/W	



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
2BVoss/2TJ	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =1mA		0.014		V/°C
		V _{GS} =10V , I _D =30A		3.5	4.4	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =15A		4.6	5.8	$\mathbf{m}\Omega$
V _{GS(th)}	Gate Threshold Voltage		1.2		2.5	V
$\mathbb{P}V_{\text{GS(th)}}$	V _{GS(th)} Temperature Coefficient	 V _{GS} =V _{DS} , I _D =250uA		-4		mV/°C
Ipss	Drain-Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =25°C			1	
		V _{DS} =24V , V _{GS} =0V , T _J =55°C			5	uA
Igss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =30A		50		S
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.7		Ω
Qg	Total Gate Charge (4.5V)			56.9		
Qgs	Gate-Source Charge	V _{DS} =15V , V _{GS} =10V , I _D =15A		13.8		nC
Qgd	Gate-Drain Charge			23.5		
Td(on)	Turn-On Delay Time			20.1		
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V ,		6.3		
Td(off)	Turn-Off Delay Time	—R _G =3.3 , I _D =1A		124.6		ns
T _f	Fall Time			15.8		
Ciss	Input Capacitance			4345		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		340		pF
Crss	Reverse Transfer Capacitance	1		225		
Is	Continuous Source Current ^{1,6}	V _G =V _D =0V , Force Current			85	Α
VsD	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1.2	V
			1			



Typical Characteristics

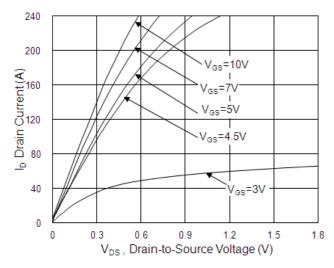


Fig.1 Typical Output Characteristics

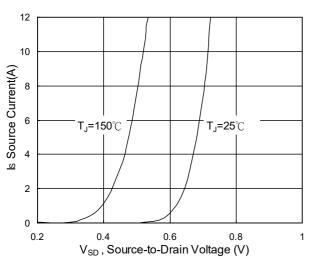


Fig.3 Forward Characteristics of Reverse

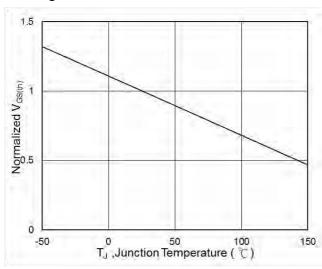


Fig.5 Normalized $V_{\text{GS(th)}}$ v.s T_{J}

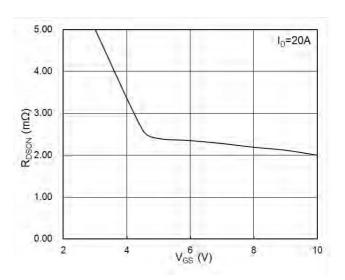


Fig.2 On-Resistance v.s Gate-Source

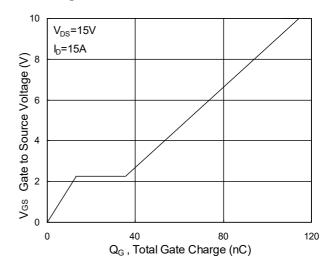


Fig.4 Gate-Charge Characteristics

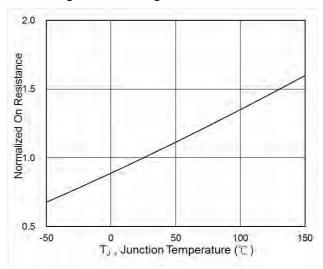


Fig.6 Normalized R_{DSON} v.s T_J



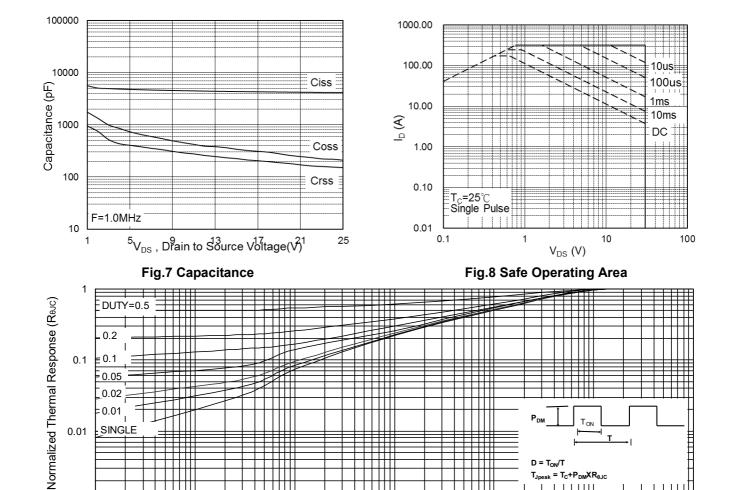
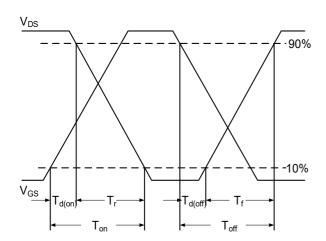


Fig.9 Normalized Maximum Transient Thermal Impedance

t, Pulse Width (s)

0.001



0.0001

0.0001

Fig.10 Switching Time Waveform

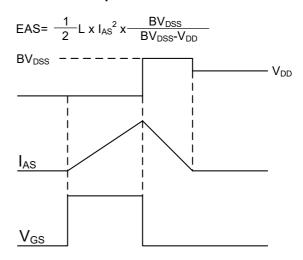
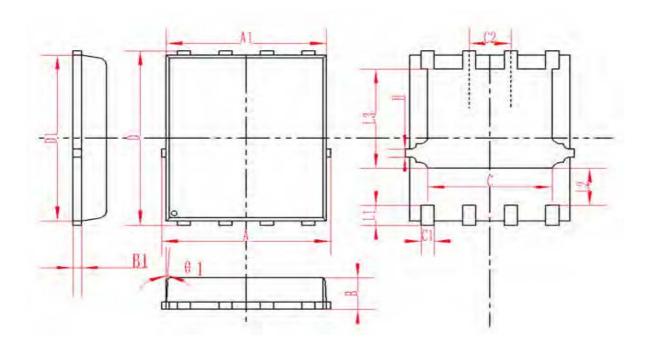


Fig.11 Unclamped Inductive Switching Waveform



DFN5X6-8L Package Information



SYMBOL	MM		INCH			
STIVIDOL	MIN	NOM	MAX	MIN	NOM	MAX
Α	5.3	5.5	5.7	0.208	0.216	0.224
A1	5.1	5.2	5.3	0.2	0.204	0.209
D	5.98	6	6.02	0.235	0.236	0.237
D1	5.85	6.05	6.25	0.23	0.238	0.246
В	0.85	0.95	1.05	0.033	0.037	0.041
B1	0.254REF		0.010REF			
С	3.95	4	4.05	0.156	0.157	0.159
C1	0.35	0.4	0.45	0.014	0.016	0.018
C2		1.27TYP			0.5TYP	
θ1	8°	10°	12°	8°	10°	12°
L1	0.63	0.64	0.65	0.025	0.025	0.026
L2	1.2	1.3	1.4	0.047	0.051	0.055
L3	3.415	3.42	3.425	0.134	0.135	0.135
Н	0.24	0.25	0.26	0.009	0.010	0.010



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